



SamHop Microelectronics Corp.



STU/D610S

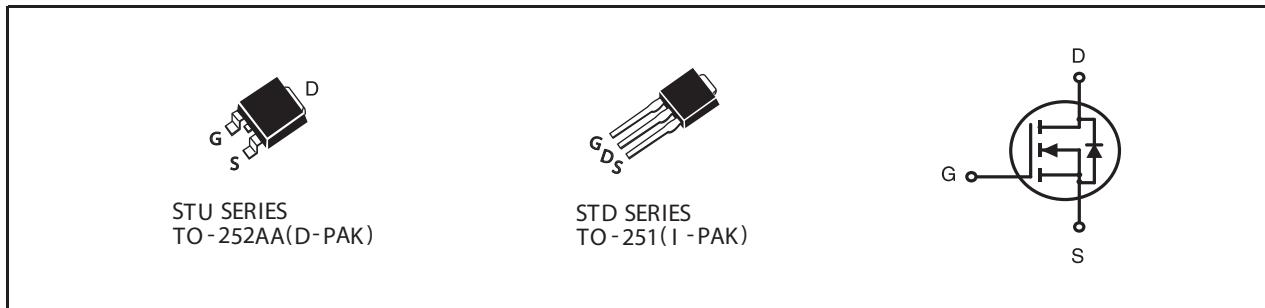
Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

| PRODUCT SUMMARY | | |
|-----------------|------|------------------|
| VDSS | ID | RDS(ON) (mΩ) Max |
| 60V | 9.5A | 240 @ VGS=10V |

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- TO-252 and TO-251 Package.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Limit | Units |
|----------------|--|------------|-------|
| V_{DS} | Drain-Source Voltage | 60 | V |
| V_{GS} | Gate-Source Voltage | ± 20 | V |
| I_D | Drain Current-Continuous ^a | 9.5 | A |
| | $T_C=25^\circ\text{C}$ | 9.5 | A |
| | $T_C=70^\circ\text{C}$ | 7.6 | A |
| I_{DM} | -Pulsed ^b | 28 | A |
| E_{AS} | Single Pulse Avalanche Energy ^d | 12.3 | mJ |
| P_D | Maximum Power Dissipation ^a | 42 | W |
| | $T_C=25^\circ\text{C}$ | 42 | W |
| | $T_C=70^\circ\text{C}$ | 27 | W |
| T_J, T_{STG} | Operating Junction and Storage Temperature Range | -55 to 150 | °C |

THERMAL CHARACTERISTICS

| | | | |
|-----------------|--|----|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case ^a | 3 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient ^a | 50 | °C/W |

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|--|------------------------------------|--|-----|------|------|-------|
| OFF CHARACTERISTICS | | | | | | |
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V , I _D =250uA | 60 | | | V |
| I _{DS} | Zero Gate Voltage Drain Current | V _{DS} =48V , V _{GS} =0V | | | 1 | uA |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±20V , V _{DS} =0V | | | ±100 | nA |
| ON CHARACTERISTICS | | | | | | |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250uA | 2 | 3 | 4 | V |
| R _{DS(ON)} | Drain-Source On-State Resistance | V _{GS} =10V , I _D =9.5A | | 185 | 240 | m ohm |
| g _{FS} | Forward Transconductance | V _{DS} =10V , I _D =9.5A | | 12.8 | | S |
| DYNAMIC CHARACTERISTICS ^c | | | | | | |
| C _{ISS} | Input Capacitance | V _{DS} =25V,V _{GS} =0V f=1.0MHz | | 348 | | pF |
| C _{OSS} | Output Capacitance | | | 34.5 | | pF |
| C _{RSS} | Reverse Transfer Capacitance | | | 17 | | pF |
| SWITCHING CHARACTERISTICS ^c | | | | | | |
| t _{D(ON)} | Turn-On Delay Time | V _{DD} =30V I _D =1A V _{GS} =10V R _{GEN} = 6 ohm | | 10.5 | | ns |
| t _r | Rise Time | | | 8.5 | | ns |
| t _{D(OFF)} | Turn-Off Delay Time | | | 15.8 | | ns |
| t _f | Fall Time | | | 4.3 | | ns |
| Q _g | Total Gate Charge | V _{DS} =30V,I _D =9.5A,V _{GS} =10V | | 4.7 | | nC |
| Q _{gs} | Gate-Source Charge | V _{DS} =30V,I _D =9.5A, V _{GS} =10V | | 1.3 | | nC |
| Q _{gd} | Gate-Drain Charge | | | 1.3 | | nC |
| DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS | | | | | | |
| V _{SD} | Diode Forward Voltage ^b | V _{GS} =0V,I _S =1A | | 0.8 | 1.3 | V |
| Notes | | | | | | |
| a.Surface Mounted on FR4 Board,t ≤ 10sec. | | | | | | |
| b.Pulse Test:Pulse Width ≤ 300us, Duty Cycle ≤ 2%. | | | | | | |
| c.Guaranteed by design, not subject to production testing. | | | | | | |
| d.Starting T _J =25°C,L=0.5mH,V _{DD} = 30V.(See Figure13) | | | | | | |

Apr,30,2010

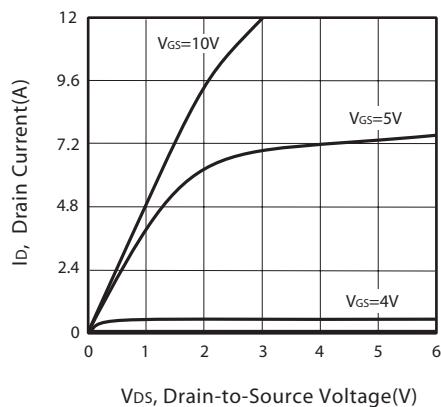


Figure 1. Output Characteristics

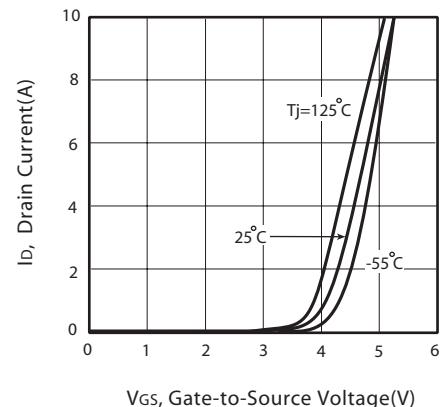


Figure 2. Transfer Characteristics

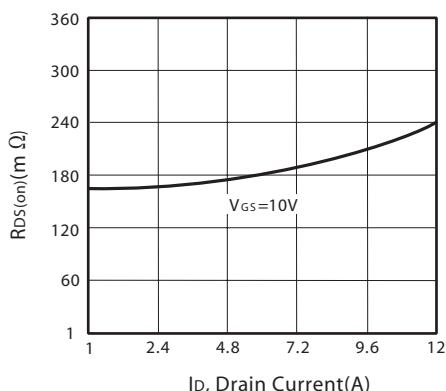


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

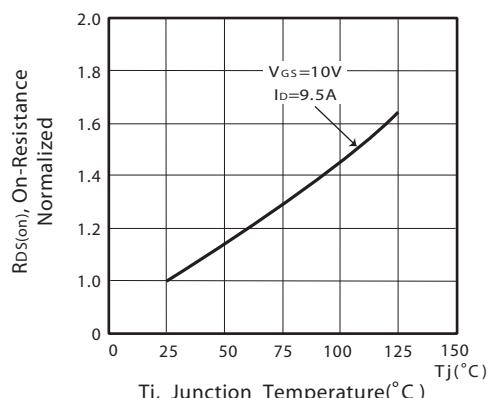


Figure 4. On-Resistance Variation with Drain Current and Temperature

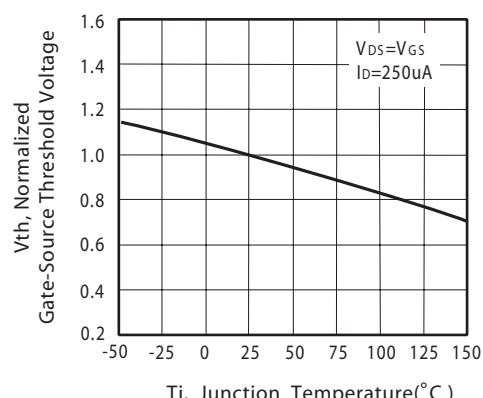


Figure 5. Gate Threshold Variation with Temperature

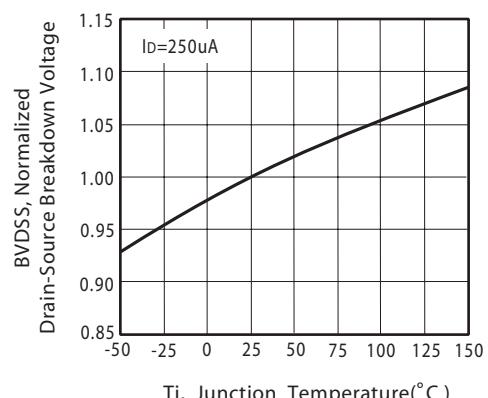
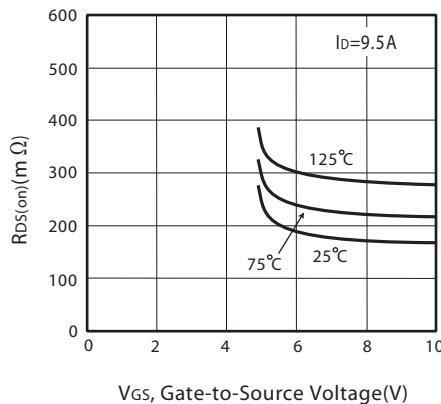
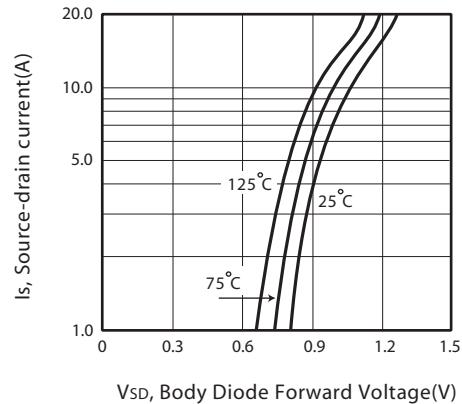


Figure 6. Breakdown Voltage Variation with Temperature



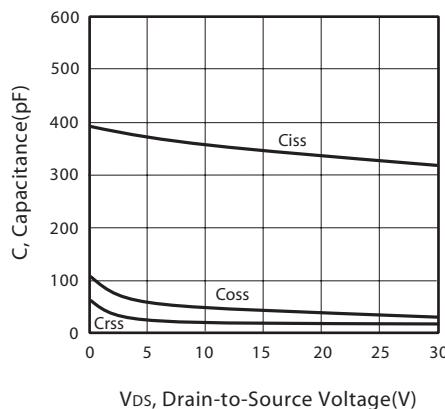
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



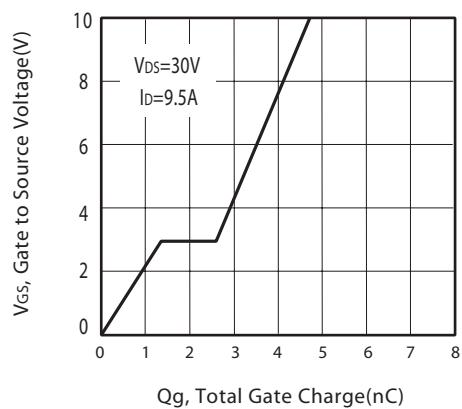
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



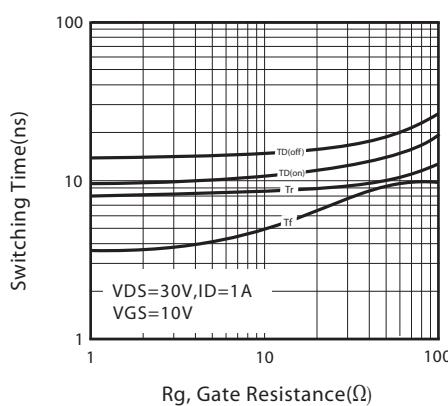
V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



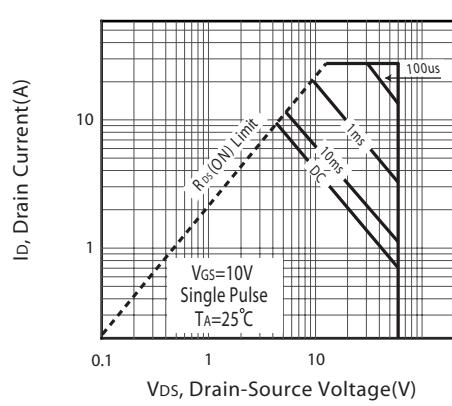
Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge



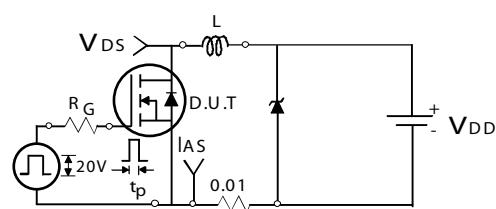
V_{DS}=30V, ID=1A
V_{GS}=10V

Figure 11. switching characteristics



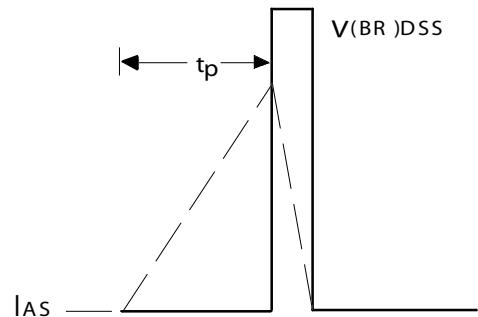
V_{GS}=10V
Single Pulse
T_A=25°C

Figure 12. Maximum Safe Operating Area



Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

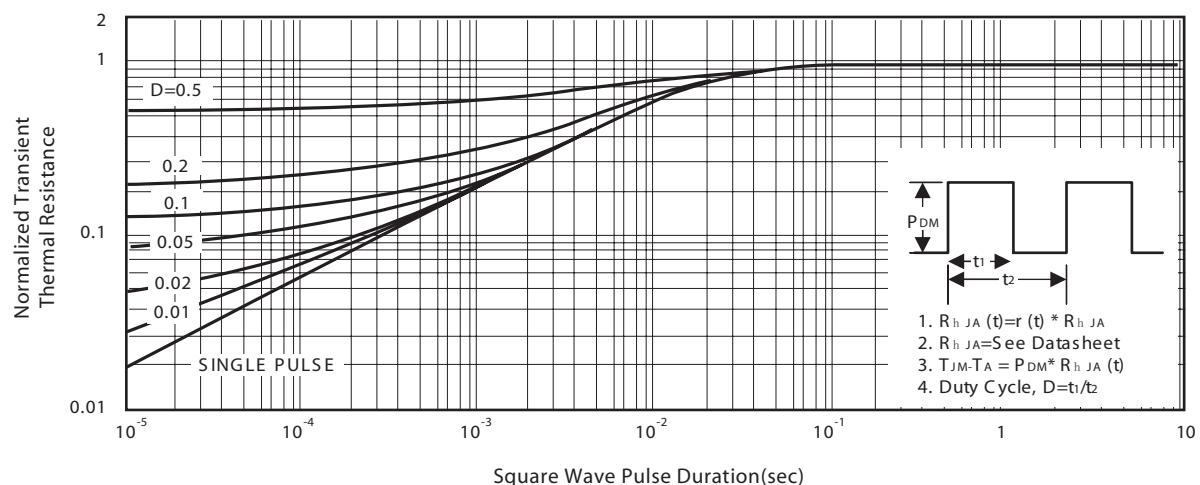
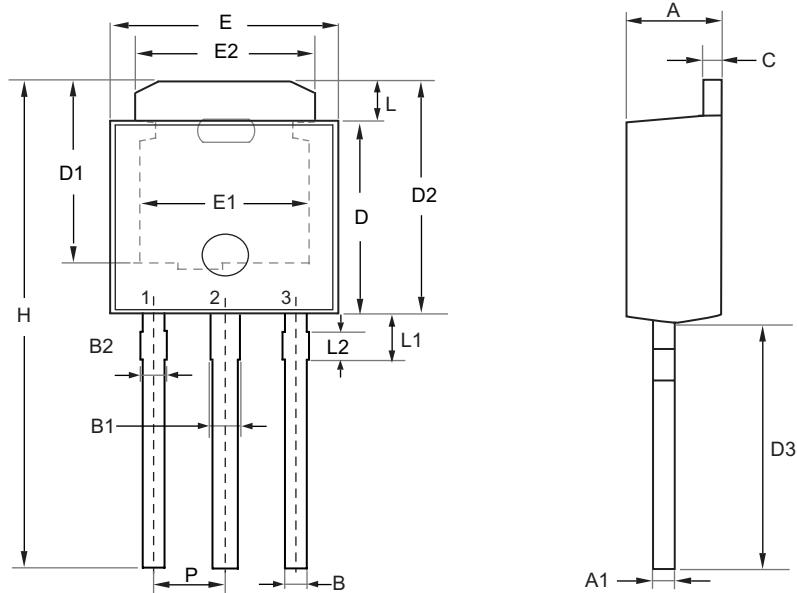


Figure 14. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS

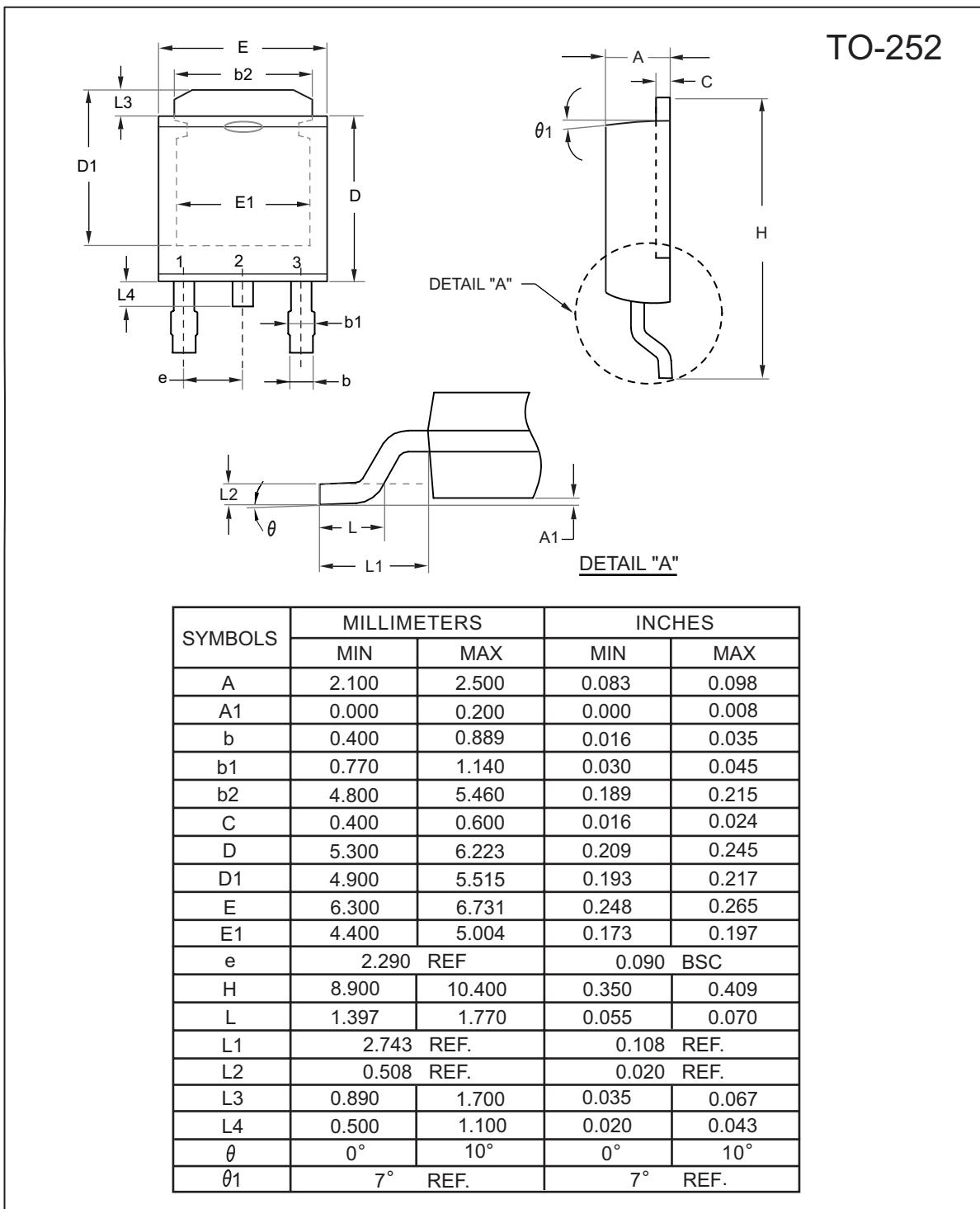
TO-251



| SYMBOL | MILLIMETERS | | INCHES | |
|--------|-------------|--------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 2.100 | 2.500 | 0.083 | 0.098 |
| A1 | 0.350 | 0.650 | 0.014 | 0.026 |
| B | 0.400 | 0.800 | 0.016 | 0.031 |
| B1 | 0.650 | 1.050 | 0.026 | 0.041 |
| B2 | 0.500 | 0.900 | 0.020 | 0.035 |
| C | 0.400 | 0.600 | 0.016 | 0.024 |
| D | 5.300 | 5.700 | 0.209 | 0.224 |
| D1 | 4.900 | 5.300 | 0.193 | 0.209 |
| D2 | 6.700 | 7.300 | 0.264 | 0.287 |
| D3 | 7.000 | 8.000 | 0.276 | 0.315 |
| H | 13.700 | 15.300 | 0.539 | 0.602 |
| E | 6.300 | 6.700 | 0.248 | 0.264 |
| E1 | 4.600 | 4.900 | 0.181 | 0.193 |
| E2 | 4.800 | 5.200 | 0.189 | 0.205 |
| L | 1.300 | 1.700 | 0.051 | 0.067 |
| L1 | 1.400 | 1.800 | 0.055 | 0.071 |
| L2 | 0.500 | 0.900 | 0.020 | 0.035 |
| P | 2.300 BSC | | 0.091 BSC | |

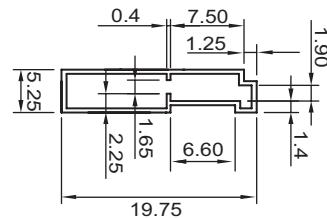
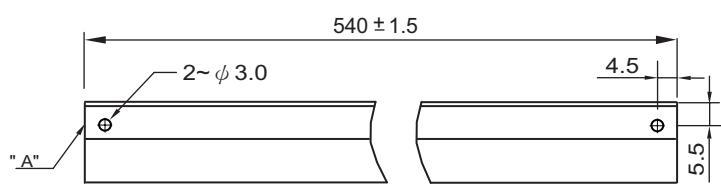
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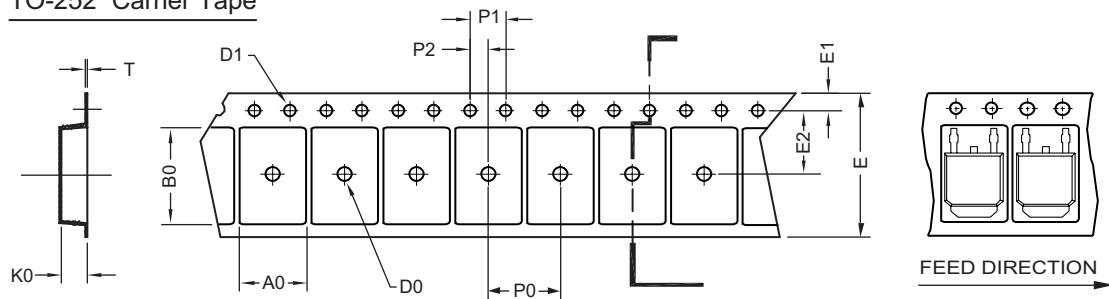


TO-251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



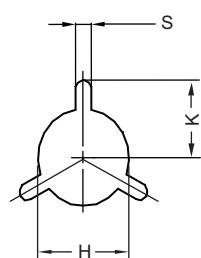
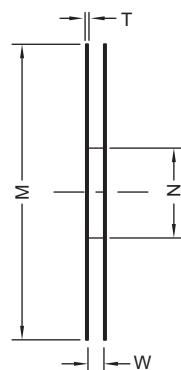
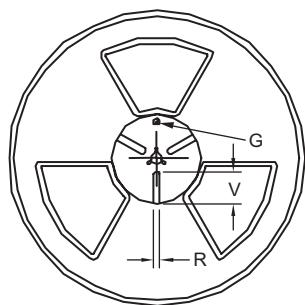
TO-252 Carrier Tape



UNIT:mm

| PACKAGE | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|-------------------|--------------|---------------|--------------|-----|-----------------------|--------------|--------------|--------------|-------------|-------------|--------------|--------------|
| TO-252 (16 mm) | 6.96 ±0.1 | 10.49 ±0.1 | 2.79 ±0.1 | ψ 2 | ψ 1.5 + 0.1 - 0 | 16.0 ±0.3 | 1.75 ±0.1 | 7.5 ±0.15 | 8.0 ±0.1 | 4.0 ±0.1 | 2.0 ±0.15 | 0.3 ±0.05 |

TO-252 Reel



UNIT:mm

| TAPE SIZE | REEL SIZE | M | N | W | T | H | K | S | G | R | V |
|-----------|-----------|----------------|---------------|----------------------|-----|--------------------------|------|--------------|-----|-----|-----|
| 16 mm | ψ 330 | ψ 330 ± 0.5 | ψ 97 ± 1.0 | 17.0 + 1.5 - 0 | 2.2 | ψ 13.0 + 0.5 - 0.2 | 10.6 | 2.0 ± 0.5 | --- | --- | --- |